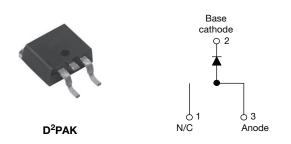
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High Performance Schottky Rectifier, 19 A



PRODUCT SUMMARY						
Package	D <sup>2</sup> PAK					
I <sub>F(AV)</sub>	19 A					
V <sub>R</sub>	15 V					
V <sub>F</sub> at I <sub>F</sub>	0.36 V					
I <sub>RM</sub> max.	522 mA at 100 °C					
T <sub>J</sub> max.	125 °C					
Diode variation	Single die					
E <sub>AS</sub>	6.75 mJ					

### FEATURES

- 125 °C T<sub>J</sub> operation ( $V_R < 5 V$ )
- · Optimized for OR-ing applications
- Ultralow forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

The VS-19TQ015SPbF Schottky rectifier has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	SYMBOL CHARACTERISTICS VALUES UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	19	А				
V <sub>RRM</sub>		15	V				
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	700	А				
V <sub>F</sub>	19 A <sub>pk</sub> , T <sub>J</sub> = 75 °C	0.32	V				
TJ	Range	-55 to +125	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-19TQ015SPbF	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	15 V				
Maximum working peak reverse voltage	V <sub>RWM</sub>	10	V			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS			
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at $T_C = 80$ °C,	19	А			
Maximum peak one cycle non-repetitive surge current	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	700	A		
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	rated V <sub>RRM</sub> applied	330			
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.50 A, L = 6 mH		6.75	mJ		
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero Frequency limited by T <sub>J</sub> maximu	1.50	А			

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ELECTRICAL SPECIFICATIONS	
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PARAMETER	SYMBOL	TEST	CONDITIONS	VALUES	UNITS	
		19 A	T.I = 25 °C	0.36	v	
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	38 A	1 ] = 23 0	0.46		
See fig. 1	VFM (")	19 A	T.I = 75 °C	0.32		
		38 A	1J=75 C	0.43		
	I <sub>RM</sub> <sup>(1)</sup>	$T_{\rm J} = 100 \ ^{\circ}\text{C}, \ V_{\rm R} = 12 \ \text{V}$		465		
Maximum reverse leakage current		T <sub>J</sub> = 100 °C, V <sub>R</sub> = 5 V		285		
See fig. 2		T <sub>J</sub> = 25 °C	V Deted V	10.5	- mA	
		T <sub>J</sub> = 100 °C	V <sub>R</sub> = Rated V <sub>R</sub>	522		
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal	2000	pF		
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs		

#### Note

<sup>(1)</sup> Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temper	rature range	TJ		-55 to +125	°C	
Maximum storage temper	ature range	T <sub>Stg</sub>		-55 to +150	Ĵ	
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation See fig. 4	1.50	°C/W	
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	0/10	
Approximate weight				2	g	
Approximate weight				0.07	oz.	
minimum				6 (5)	kgf∙cm	
Mounting torque –	maximum			12 (10)	(lbf ⋅ in)	
Marking device	Marking device		Case style D <sup>2</sup> PAK	19TQ	015S	

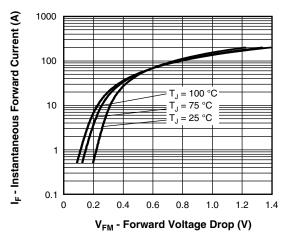


Fig. 1 - Maximum Forward Voltage Drop Characteristics

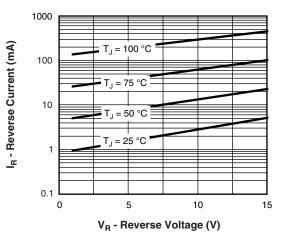


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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## VS-19TQ015SPbF

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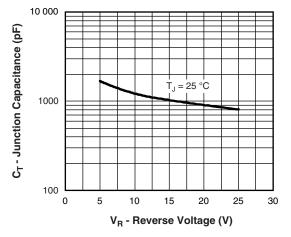


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

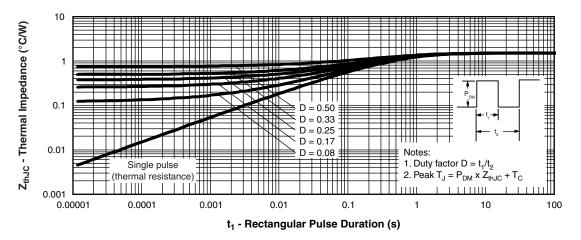
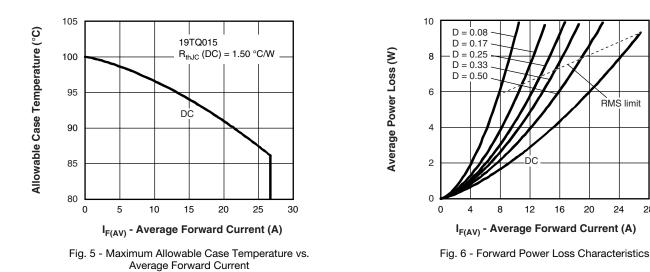


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



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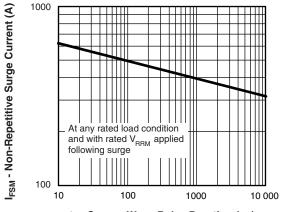
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# VS-19TQ015SPbF

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t<sub>p</sub> - Square Wave Pulse Duration (μs)



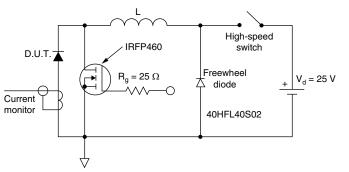
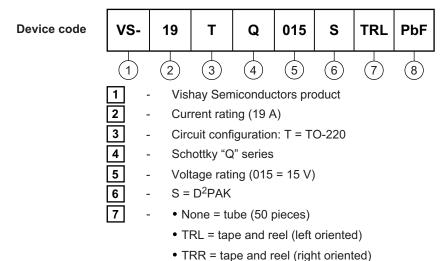


Fig. 8 - Unclamped Inductive Test Circuit

### **ORDERING INFORMATION TABLE**



- PbF = lead (Pb)-free

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LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95014					
Part marking information	www.vishay.com/doc?95008					
Packaging information	www.vishay.com/doc?95032					
SPICE model	www.vishay.com/doc?96005					

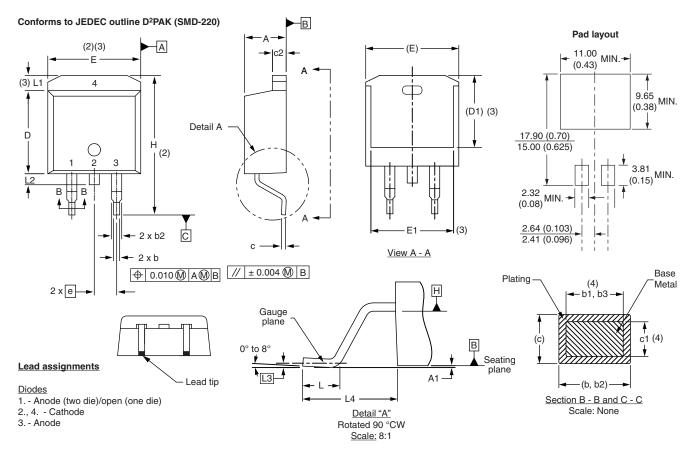
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Vishay Semiconductors

# D<sup>2</sup>PAK, TO-262



### DIMENSIONS - D<sup>2</sup>PAK in millimeters and inches

SHA

SYMBOL	MILLIN	MILLIMETERS		INCHES	
STNIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

INCHES

MILLIMETERS

<sup>(7)</sup> Outline conforms to JEDEC outline TO-263AB

#### Notes

 $^{(1)}\,$  Dimensioning and tolerancing per ASME Y14.5 M-1994  $\,$ 

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

- $^{(3)}\,$  Thermal pad contour optional within dimension E, L1, D1 and E1
- <sup>(4)</sup> Dimension b1 and c1 apply to base metal only
- <sup>(5)</sup> Datum A and B to be determined at datum plane H
- <sup>(6)</sup> Controlling dimension: inch

Document Number: 95014 Revision: 31-Mar-09

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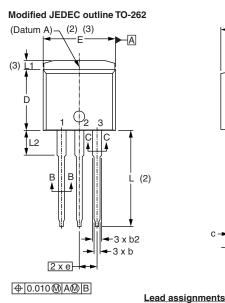
## **Outline Dimensions**

### Vishay Semiconductors

D<sup>2</sup>PAK, TO-262



#### DIMENSIONS - TO-262 in millimeters and inches

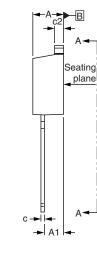


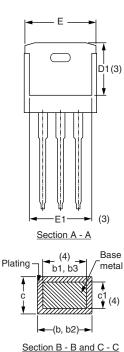
Lead tip

Diodes

3. - Anode

2., 4. - Cathode





Scale: None

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the

SYMBOL	MILLIMETERS		INC	INCHES		
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.10	0 BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

1. - Anode (two die)/open (one die)

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

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actual package outline

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